Circcuit

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1. voltage source | soovee

1. convent

III. Pesiston

I. Inductor " load.

I capaciton.

1 Active element -> (IT (I(3) TO) TATO FIRS (2) Pasive element -> Active -200 200 AGA (ALEXA) A

* lesistion -> _M -> 12 lonn

& Induction -> - norm -> Hanney 174

+ capacitor -> C -> favade (F

@ Current source

natype: न न कलाडी व्यक्त I. As desiring I regelive to dange 9 . 50 ma-P-type उ दिलाकी लीक I. Al doping
I. Positive on Songara Hole TO W. 3-6 BT.

Diode: P 3 nr - Type ga sission foat i ac page De co convents rear Rectifiens. orking principle P-N + Junction diode: 10 most from prillimos 1. Majority carrier II. Minorcity carcicion. Depution layer -> 27 812(7) DODD > majority carriers (EL) -> Minorcity carerciers (HOLLES) BBB majorcity (woles.)

minority correctors (Ele ent.

Biasing a pr jonation:

O Foreward biasing: when external d. .

voltage applied to the joination is

in such a direction that it

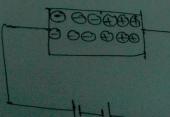
canecks the potential barcreier, thus

perconitting charment flow, 9t is called

foreward biasing.

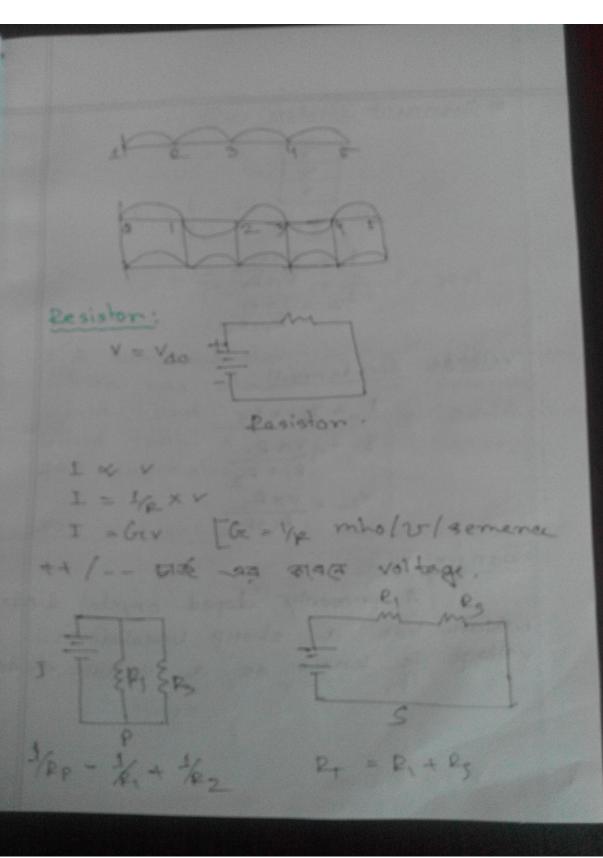
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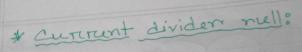
Reverge biasing: when the external d.c voltage applied to the Junction is in such a direction that potential barrier is increased it in called theverge biosing



* characterestics current of P-N Juction diode or, VI charcacterestice cative. or, volt. Indeal diode/ Practical diode IL TWENT CONTRACT 0 (यात सामाम) VE अय चित्र flow arm 20 1 were voltage PIV: Peak Invench voltage & voltage 27

* knee voltage: It is the forwared voltage at which the autricent through the Junction starts to increase respirit, Walt wave * Diode walf wave pulsating De Full wave: 1. Center full wave rectiten 2. full wave breidge rectifer.







$$I_1 = \frac{I \times R_2}{R_1 + R_2}$$

$$I_2 = \underbrace{I \times P_1}_{P_1 + P_2}$$

voltage dividental!

$$I = I_1 = I_2$$

$$\frac{\sqrt{4}}{\sqrt{1 + 2}} = \frac{\sqrt{2}}{\sqrt{1 + 2}}$$

$$\sqrt{2} = \frac{\sqrt{2}}{\sqrt{1 + 2}}$$

Zenar Diede:

A properly doped crystal diode which has a sharep breakdown voltage is know as a zenare diode * A coh 60 6 a ga

$$V_{2} = \frac{V_{2}}{I_{2}}$$

$$V_{2} = \frac{V_{2}}{I_{2}}$$

$$V_{3} = \frac{F_{1} - F_{0}}{(I_{2})min^{2}(I)}$$

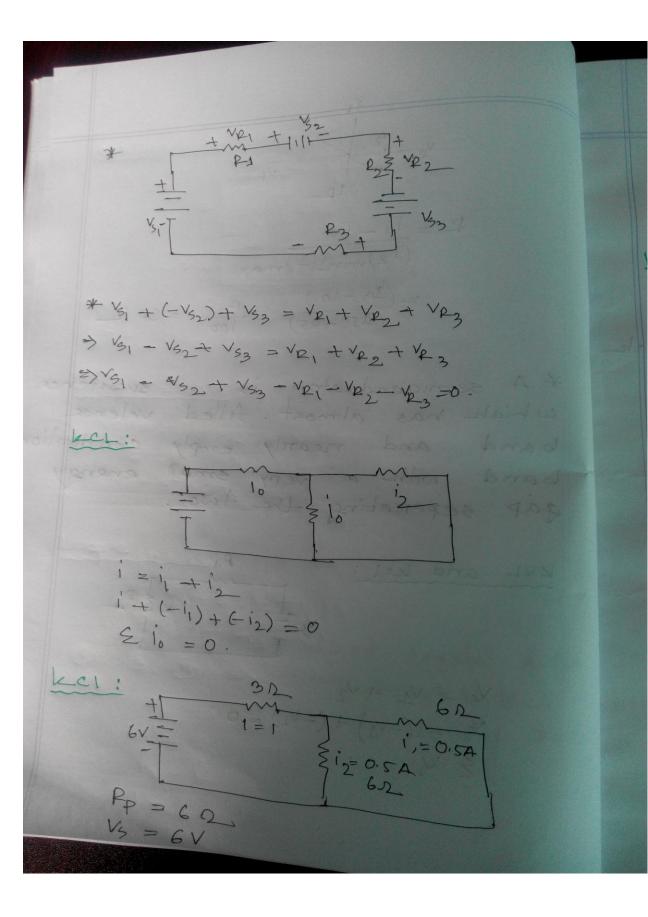
$$= \frac{(X_{3} - 10)}{(A_{5} + 85)} = \frac{13}{100} = 30 \Omega$$

* A semiconductor is a substance which has almost filled valence band and nearly empty conduction band with a very small energy gap separcating the two.

KVL and kel:

V, = V2 P2

 $\frac{\sqrt{3}}{3} = \frac{\sqrt{4}}{4} + \frac{\sqrt{2}}{4}$ $\frac{\sqrt{3}}{3} = (-\frac{\sqrt{4}}{4}) + (-\frac{\sqrt{2}}{2}) = 0$ $\frac{2}{3} + \frac{\sqrt{4}}{4} = 0$



1 A = 0.5 + 0.5 = 1 A

KYL:

 $6V = IP_1 + IP_2$ $= 1 \times 3 + 1 \times 3$ = 6V

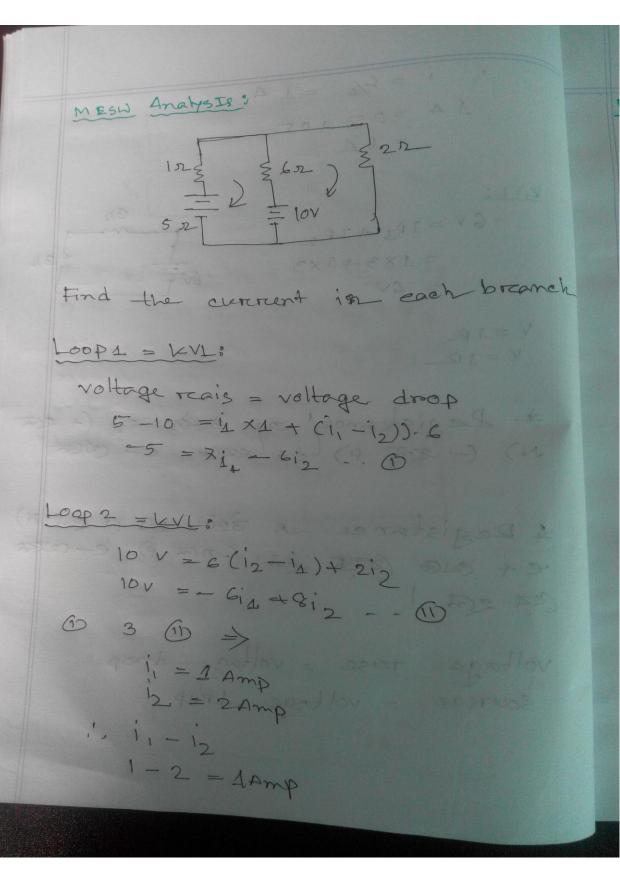
32 6VT 332

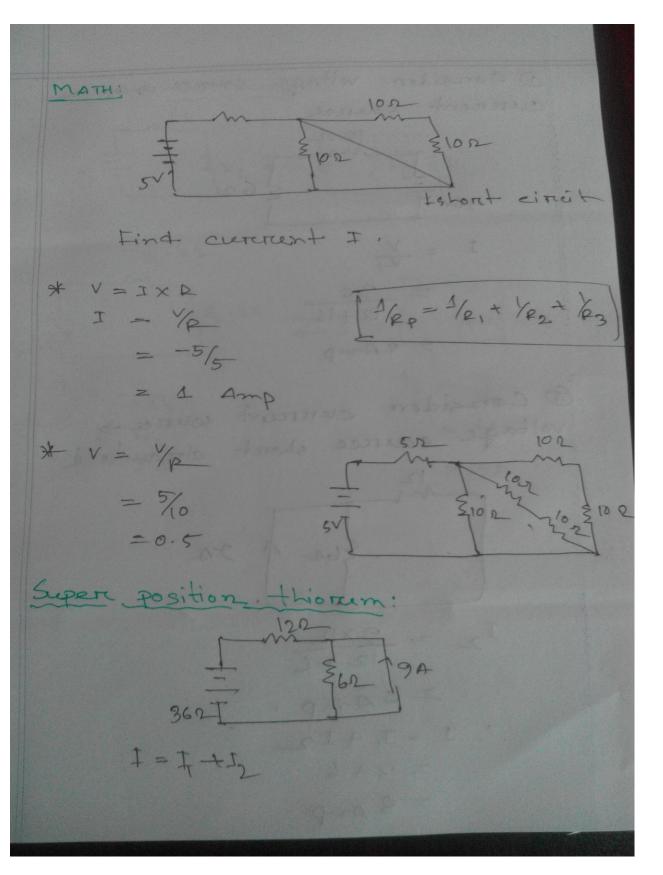
N=IB N=IB

* Degistance/ 27 3000 20 (+ 2000 N) (- 2000 P) (e+ 1 CORRE e- COTCE

A Degistarce _ A 3681 25 (+ 26 N)
e + @100 (250 26 1 (- 250 P) e- (2500)
CA 261 1

voltage reise = voltage drop source = voltage drop





O consider voltage source >> open = 2Amp @ consider current source > voltage source short circuite d $I_2 = \frac{9 \times 12}{12 + 6}$ = 246 = 8 Amp

